

Application Data Sheet

Application Information

Application number::	Unassigned
Filing Date::	01/07/2004
Application Type::	Regular
Subject Matter::	Utility
Suggested classification::	
Suggested Group Art Unit::	
CD-ROM or CD-R?::	None
Computer Readable Form (CRF)?::	No
Title::	III-V GROUP NITRIDE SYSTEM SEMICONDUCTOR SUBSTRATE
Attorney Docket Number::	035532-0138
Request for Early Publication?::	No
Request for Non-Publication?::	No
Suggested Drawing Figure::	
Total Drawing Sheets::	4
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

Applicant Information

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Masatomo
Family Name::	SHIBATA
City of Residence::	Tokyo
Country of Residence::	Japan

Street of mailing address:: c/o HITACHI CABLE, LTD.
6-1, Otemachi 1-chome
Chiyoda-ku, Tokyo
Country of mailing address:: Japan

Correspondence Information

Correspondence Customer Number:: 22428
E-Mail address:: PTOMailWashington@Foley.com

Representative Information

Representative Customer Number::	22428	
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Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::

Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-368828	10/29/2003	Yes

Assignee Information

Assignee name:: HITACHI CABLE, LTD.